NSN 5961-00-520-3453

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-520-3453 **Inclosure Material:** Metal **End Application:** Aircraft, galaxy c-5 **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method: Terminal Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 190.0 collector to base voltage/static/emitter open and 180.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector absolute **Special Features:** Junction pattern arrangement: npn; weapon system essential **Test Data Document:** 97896-341-0287 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) and 97896-341-0276 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No